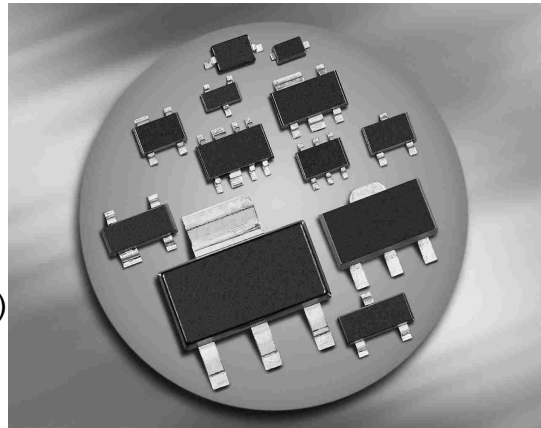
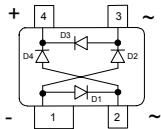


**Low VF Schottky Diode Array**

- Reverse voltage: 40 V
- Forward current: 0.2 A
- Small diode quad array for polarity independence, reverse polarity protection and low loss bridge rectification
- Very low forward voltage: 0.55 @ 0.1 A (per diode)
- Fast switching
- Pb-free (ROHS compliant) package
- Qualified according AEC Q101


**BAS4002A-RPP**


Type	Package	Configuration	Marking
BAS4002A-RPP*	SOT143	bridge	E9s

\* Preliminary Data

**Maximum Ratings** at  $T_A = 25\text{ °C}$ , unless otherwise specified

Parameter	Symbol	Value	Unit
Diode reverse voltage <sup>1)</sup>	$V_R$	40	V
Peak reverse voltage <sup>1)</sup>	$V_{RM}$	40	
RMS reverse voltage <sup>1)</sup>	$V_{R(RMS)}$	28	
Forward current <sup>1)</sup> , $T_S \leq 124\text{ °C}$	$I_F$	200	mA
Non-repetitive peak surge forward current ( $t \leq 10\text{ ms}$ )	$I_{FSM}$	2	A
Junction temperature	$T_j$	150	°C
Storage temperature	$T_{stg}$	-65 ... 150	

<sup>1)</sup>For  $T_A > 25\text{ °C}$  the derating of  $V_R$  and  $I_F$  has to be considered.

**Thermal Resistance**

Parameter	Symbol	Value	Unit
Junction - soldering point <sup>1)</sup>	$R_{thJS}$	≤ 130	K/W

**Electrical Characteristics at  $T_A = 25^\circ\text{C}$ , unless otherwise specified**

Parameter	Symbol	Values			Unit
		min.	typ.	max.	

**DC Characteristics**

Reverse current <sup>2)</sup> (per diode)	$I_R$				$\mu\text{A}$
$V_R = 30\text{ V}$		-	-	2	
$V_R = 40\text{ V}$		-	-	10	
Forward voltage <sup>2) 3)</sup> (per diode)	$V_F$				V
$I_F = 10\text{ mA}$		-	0.39	0.44	
$I_F = 60\text{ mA}$		-	0.49	0.55	
$I_F = 100\text{ mA}$		-	0.55	0.62	
$I_F = 200\text{ mA}$		-	0.69	0.79	

**AC Characteristics**

Diode capacitance (per diode)	$C_T$	-	2	5	pF
$V_R = 5\text{ V}$ , $f = 1\text{ MHz}$					

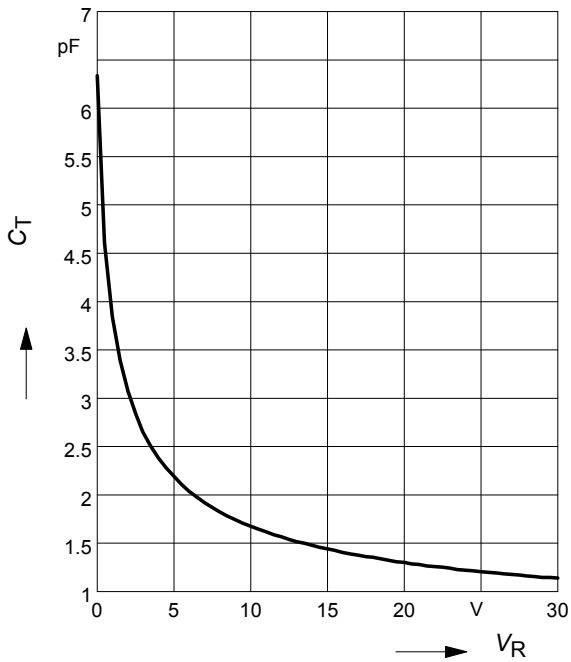
<sup>1</sup>For calculation of  $R_{thJA}$  please refer to Application Note Thermal Resistance

<sup>2</sup>Pulsed test,  $t_p = 300\ \mu\text{s}$ ;  $D = 0.01$

<sup>3</sup>When used as shown for Reverse Polarity Protection (RPP, see page 4), the voltage available to the circuit being protected will be two diode drops below the power supply voltage. In other words, the supply current will pass through two diodes.

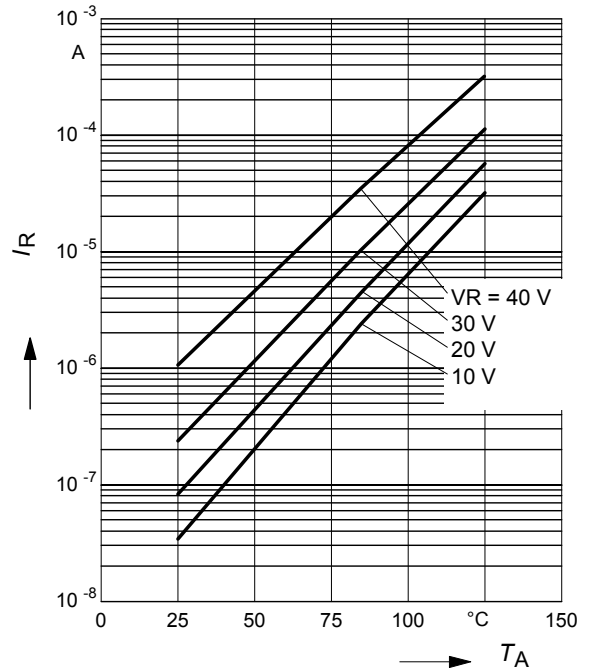
Diode capacitance  $C_T = f(V_R)$

$f = 1\text{MHz}$  (per diode)



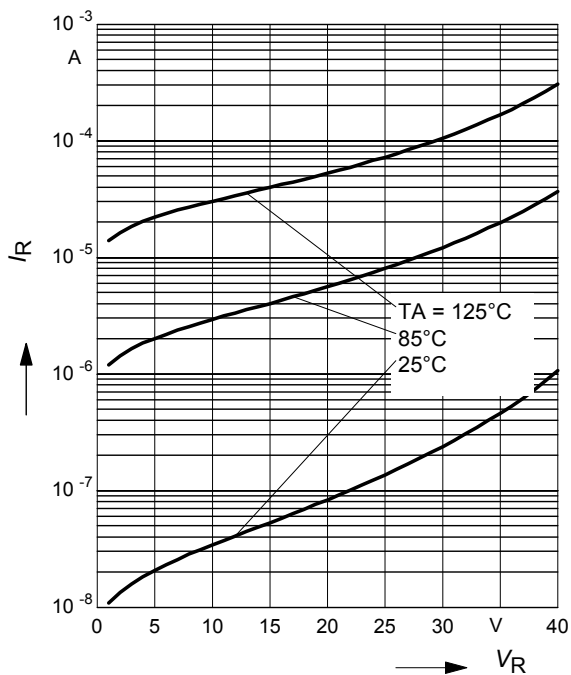
Reverse current  $I_R = f(T_A)$

$V_R = \text{Parameter}$  (per diode)



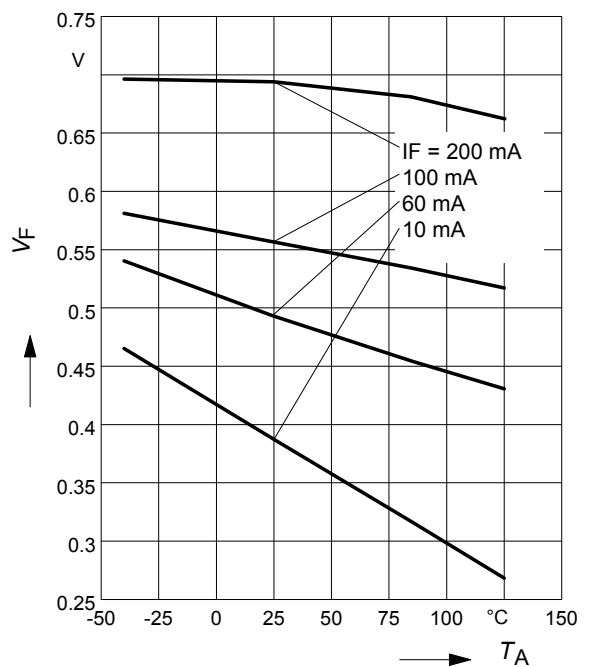
Reverse current  $I_R = f(V_R)$

$T_A = \text{Parameter}$  (per diode)

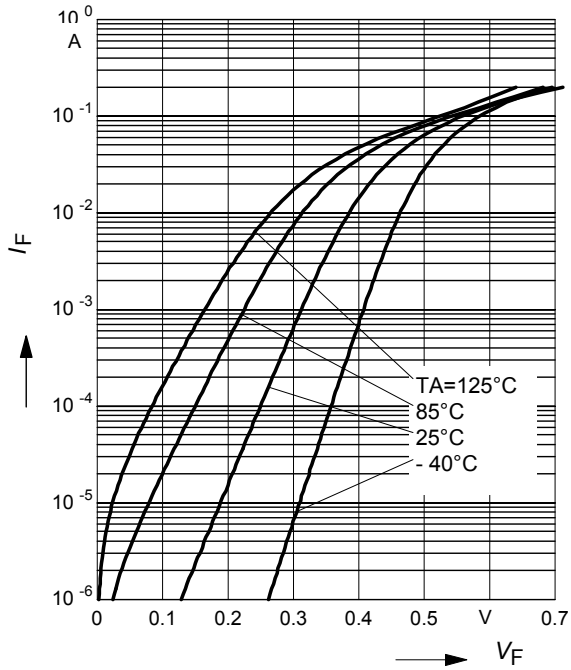


Forward Voltage  $V_F = f(T_A)$

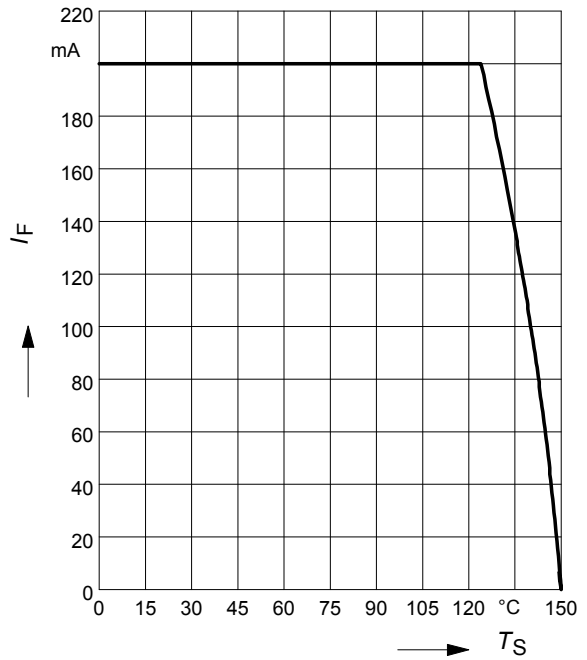
$I_F = \text{Parameter}$  (per diode)



**Forward current  $I_F = f(V_F)$**   
(per diode)

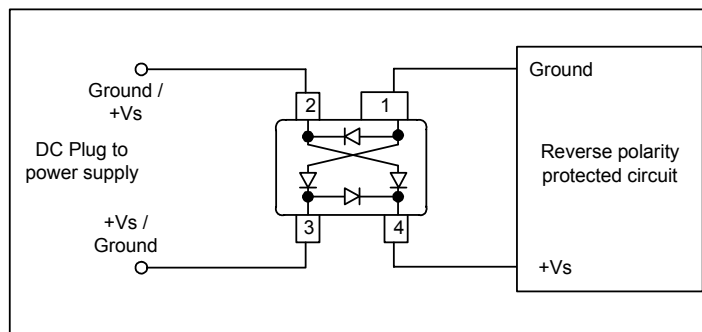


**Forward current  $I_F = f(T_S)$**   
BAS4002-RPP

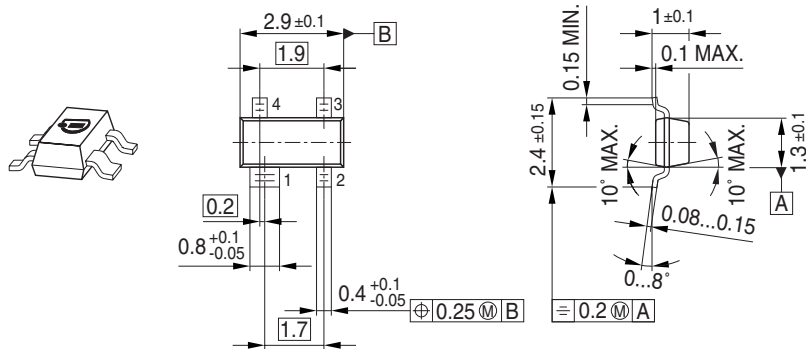


**Application example BAS4002A-RPP**

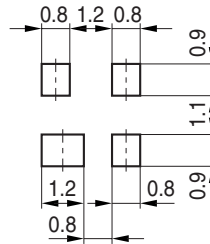
Advanced Reverse Polarity Protection(RPP): due to diode orientation, circuit at the right will be protected from damage and will also function normally in the event reverse polarity is applied to pins 2 and 3 of the BAS4002A-RPP.



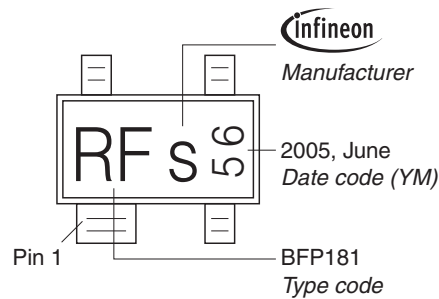
Package Outline



Foot Print

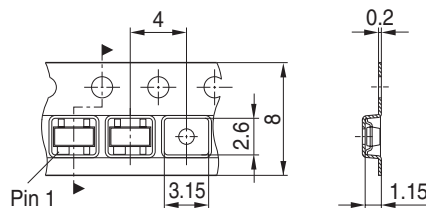


Marking Layout (Example)



Standard Packing

Reel  $\phi$ 180 mm = 3.000 Pieces/Reel  
 Reel  $\phi$ 330 mm = 10.000 Pieces/Reel



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